

SiC Schottky Barrier Diode

V_R	1200V
I _F	5A
Q_C	17nC

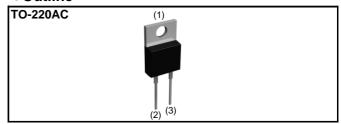
Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

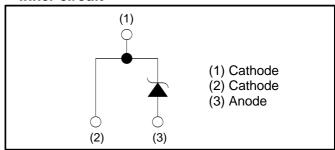
Construction

Silicon carbide epitaxial planer type

Outline



●Inner circuit



Packaging specifications

		
Type	Packaging	Tube
	Reel size (mm)	-
	Tape width (mm)	-
	Basic ordering unit (pcs)	50
	Taping code	С
	Marking	SCS205KG

● Absolute maximum ratings (Ti = 25°C)

Parameter	Symbol	Value	Unit	
Reverse voltage (repetitive peak)	V_{RM}	1200	V	
Reverse voltage (DC)	V _R	1200	V	
Continuous forward current	I _F	5* ¹	А	
		23* ²	А	
Surge no repetitive forward current	I _{FSM}	87* ³	А	
		18* ⁴	А	
Repetitive peak forward current	I _{FRM}	25* ⁵	А	
Total power disspation	P _D	88* ⁶	W	
Junction temperature	Tj	175	°C	
Range of storage temperature	Tstg	-55 to +175	°C	

^{*1} Tc=150°C *2 PW=8.3ms sinusoidal, Tj=25°C *3 PW=10μs square, Tj=25°C

^{*4} PW=8.3ms sinusoidal, Tj=150°C *5 Tc=100°C, Tj=150°C, Duty cycle=10% *6 Tc=25°C

●Electrical characteristics (Tj = 25°C)

Parameter	Symbol	Conditions	Values			Linit
raiametei		Conditions	Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =0.1mA	1200	-	-	V
Forward voltage	V _F	I _F =5A,Tj=25°C	-	1.4	1.6	V
		I _F =5A,Tj=150°C	-	1.8	-	V
		I _F =5A,Tj=175°C	-	1.9	-	V
Reverse current	I _R	V _R =1200V,Tj=25°C	-	5	100	μΑ
		V _R =1200V,Tj=150°C	-	40	1	μΑ
		V _R =1200V,Tj=175°C	-	65	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	270	-	pF
		V _R =800V,f=1MHz	-	21	-	pF
Total capacitive charge	Qc	V _R =800V,di/dt=500A/μs	-	17	-	nC
Switching time	tc	V _R =800V,di/dt=500A/μs	1	15	-	ns

Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	$R_{\text{th(j-c)}}$	-	-	1.5	1.7	°C/W

•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

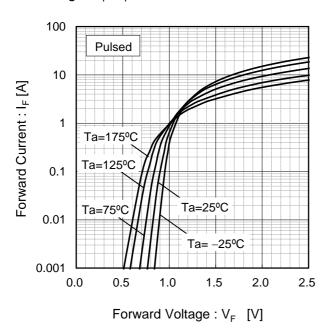


Fig.2 V_F - I_F Characteristics

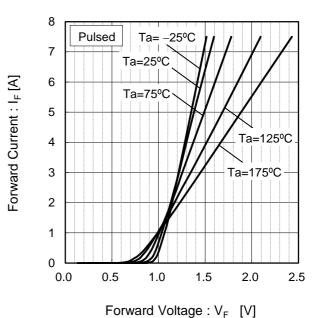


Fig.3 V_R - I_R Characteristics

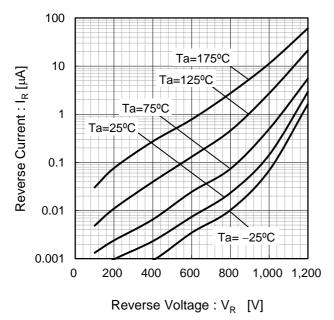
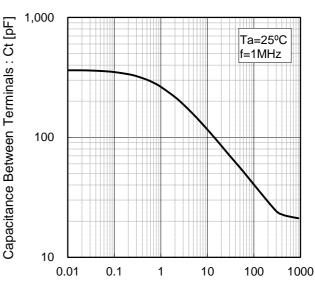


Fig.4 V_R-Ct Characteristics



•Electrical characteristic curves

Fig.5 Thermal Resistance vs. Pulse Width

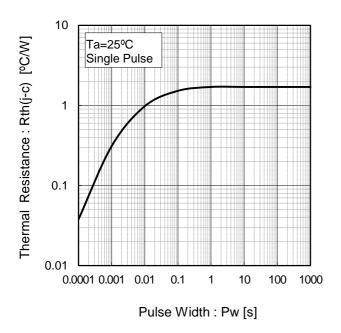


Fig.6 Power Dissipation

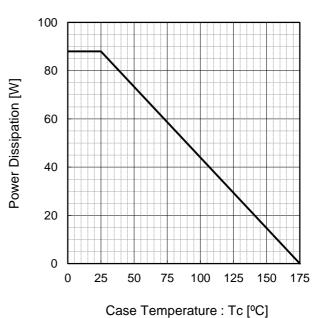


Fig.7 Ip-Tc Derating Curve

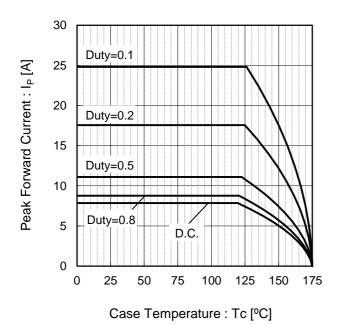
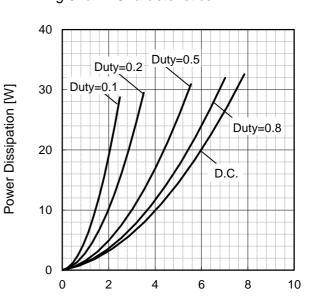


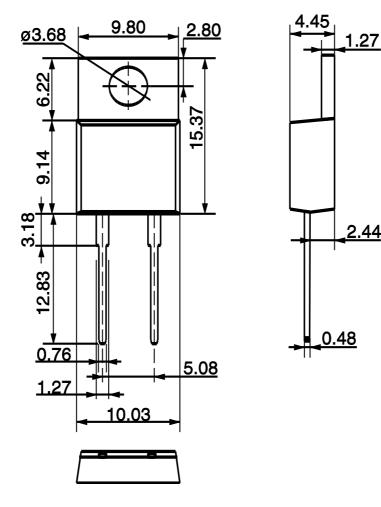
Fig.8 Io-Pf Characteristics



Average Rectified Forward Current : Io [A]

●Dimensions (Unit:mm)

TO-220AC



Notes

- 1) The information contained herein is subject to change without notice.
- Before you use our Products, please contact our sales representative and verify the latest specifications:
- 3) Although ROHM is continuously working to improve product reliability and quality, semiconductors can break down and malfunction due to various factors. Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Poducts beyond the rating specified by ROHM.
- 4) Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.
- 5) The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM or any other parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use of such technical information.
- 6) The Products specified in this document are not designed to be radiation tolerant.
- 7) For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative: transportation equipment (i.e. cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, servers, solar cells, and power transmission systems.
- 8) Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.
- 9) ROHM shall have no responsibility for any damages or injury arising from non-compliance with the recommended usage conditions and specifications contained herein.
- 10) ROHM has used reasonable care to ensur the accuracy of the information contained in this document. However, ROHM does not warrants that such information is error-free, and ROHM shall have no responsibility for any damages arising from any inaccuracy or misprint of such information.
- 11) Please use the Products in accordance with any applicable environmental laws and regulations, such as the RoHS Directive. For more details, including RoHS compatibility, please contact a ROHM sales office. ROHM shall have no responsibility for any damages or losses resulting non-compliance with any applicable laws or regulations.
- 12) When providing our Products and technologies contained in this document to other countries, you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.
- This document, in part or in whole, may not be reprinted or reproduced without prior consent of ROHM.



Thank you for your accessing to ROHM product informations.

More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/